

# 2231 HW 7

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## 1

The bound surface charge density is  $\sigma_b = P \cdot \hat{n}$  and the bound volume charge density is  $\rho_b = -\nabla \cdot \vec{P}$ . The sum of the totals of these two charges must be zero, i.e.

$$q = \int_{\partial V} \sigma_b dA + \int_V \rho_b dV = \int_{\partial V} 1 \vec{P} \cdot \hat{n} dA - \int_V 1 \nabla \cdot \vec{P} dV$$

This is the right half of an integration by parts, with the ones inserted to make correspondence with the canonical statement obvious. The associated left side is

$$\int_V \vec{P} \cdot \nabla 1 dV$$

which is clearly zero, since  $\nabla 1 = 0$ .

## 2

The electric field inside the first configuration without the dielectric is  $\frac{\sigma}{\epsilon_0}$ . In the dielectric, it is  $\frac{\sigma}{\epsilon}$ , and integrating piecewise to find the potential we obtain  $V = \frac{\sigma d}{2\epsilon_0} + \frac{\sigma d}{2\epsilon}$ . Writing out the charge density as  $\frac{Q}{A}$  and factoring out  $2\epsilon_0$ , this becomes  $V = \frac{Qd}{2\epsilon_0 A} \left(1 + \frac{\epsilon_0}{\epsilon}\right)$ ; the corresponding capacitance is  $C = \frac{Q}{V} = \frac{2\epsilon_0 A}{d(1+\epsilon_0/\epsilon)}$ . This differs from the vacuum value of  $C = \frac{A\epsilon_0}{d}$  by a factor of  $\frac{2}{1+1/\epsilon_r}$ .

For the second configuration, we instead express  $Q$  in terms of  $V$ . In the region without the dielectric,  $E = \frac{\sigma}{\epsilon_0} \Leftrightarrow \sigma = \frac{\epsilon_0 V}{d}$ . In the other region,  $\sigma' = \frac{\epsilon V}{d}$ . The total charge is then  $Q = \frac{A}{2}\sigma + \frac{A}{2}\sigma' = \frac{\epsilon_0 AV}{2d} + \frac{\epsilon AV}{2d}$ . Dividing by  $V$  and factoring out  $\epsilon_0$ ,  $C = \frac{\epsilon_0 A}{2d} \left(1 + \frac{\epsilon}{\epsilon_0}\right)$ . This differs from the vacuum capacitance by a factor of  $\frac{1+\epsilon/\epsilon_0}{2}$ .

The calculations for each of the values of interest have been all but done already, so we present them without comment:

$$E_a = \begin{cases} \frac{-2(\epsilon+\epsilon_0)V}{\epsilon d} \hat{z} & \text{in the dielectric} \\ \frac{-2(\epsilon+\epsilon_0)V}{\epsilon_0 d} \hat{z} & \text{in the air} \end{cases}$$
$$E_b = \begin{cases} -\frac{V}{d} \hat{z} & \text{in the air} \\ -\frac{V}{d} \hat{z} & \text{in the dielectric} \end{cases}$$

$$\begin{aligned}
P_a &= \begin{cases} 0 & \text{in the air} \\ \epsilon(\epsilon_r - 1) \left( \frac{-2(\epsilon + \epsilon_0)V}{\epsilon d} \hat{z} \right) & \text{in the dielectric} \end{cases} \\
P_b &= \begin{cases} 0 & \text{in the air} \\ \epsilon(\epsilon_r - 1) \left( -\frac{V}{d} \hat{z} \right) & \text{in the dielectric} \end{cases} \\
D_a &= \begin{cases} \epsilon_0 \frac{-2(\epsilon + \epsilon_0)V}{\epsilon d} \hat{z} & \text{in the air} \\ \epsilon_0 \frac{-2(\epsilon + \epsilon_0)V}{\epsilon_0 d} + \epsilon(\epsilon_r - 1) \frac{-2(\epsilon + \epsilon_0)V}{\epsilon_0 d} \hat{z} & \text{in the dielectric} \end{cases} \\
D_b &= \begin{cases} -\frac{V}{b} \hat{z} & \text{in the air} \\ -\frac{V}{b} \hat{z} + \epsilon(\epsilon_r - 1) \left( -\frac{V}{d} \right) \hat{z} & \text{in the dielectric} \end{cases} \\
\sigma_{fa} &= -\nabla \cdot P_a = 0, \\
\sigma_{ba} &= P_a \cdot \hat{n} = \epsilon(\epsilon_r - 1) \left( \frac{-2(\epsilon + \epsilon_0)V}{\epsilon d} \right) \\
\sigma_{fb} &= -\nabla \cdot P_b = 0 \\
\sigma_{bb} &= P_b \cdot \hat{n} = \epsilon(\epsilon_r - 1) \left( -\frac{V}{d} \right)
\end{aligned}$$

### 3

Since the displacement follows Gauss's law with the free charge, we have

$$4\pi r^2 D = q \Leftrightarrow D = \frac{q}{4\pi r^2}$$

Since  $D = \epsilon E$ , we can calculate  $E$  as

$$\vec{E} = \begin{cases} \frac{q}{4\pi\epsilon r^2} \hat{r}, & r \leq R \\ \frac{q}{4\pi\epsilon_0 r^2} \hat{r} & r > R \end{cases}$$

We can write  $P = \epsilon_0 \chi_e E$ , so

$$P = \begin{cases} \frac{\epsilon_0 \chi_e q}{4\pi\epsilon r^2} \hat{r} & r \leq R \\ \frac{\chi_e q}{4\pi r^2} \hat{r} & r > R \end{cases}$$

For the bound charge, we have since  $P$  is radial

$$\sigma_b = P \cdot \hat{n} = P$$

Totalling this density over the surface area of the sphere,

$$q_b = 4\pi R^2 \left( \frac{\epsilon_0 \chi_e q}{4\pi\epsilon R^2} \right) = \frac{\chi_e}{1 + \chi_e} q$$

The corresponding negative charge is clustered at the center of the dielectric near the point charge.

## 4

Like above, we may calculate the electric field via Gauss's law on the displacement.

$$D = \begin{cases} \frac{Q}{4\pi r^2} \hat{r}, & r > b \\ \frac{Q}{4\pi r^2} \hat{r}, & a < r < b \\ 0, & r < a \end{cases}$$

The electric field is then, employing  $\epsilon = \epsilon_0(1 + \chi_e)$

$$E = \frac{D}{\epsilon} = \begin{cases} \frac{Q}{4\pi\epsilon_0 r^2} \hat{r}, & r > b \\ \frac{Q}{4\pi\epsilon r^2} \hat{r}, & a \leq r \leq b \\ 0, & r < a \end{cases}$$

The energy of the configuration is

$$\begin{aligned} W &= \frac{1}{2} \int_{\mathbb{R}^3} E \cdot D dV = \frac{1}{2} \int_0^\pi \int_0^{2\pi} \left( \int_0^a + \int_a^b + \int_b^\infty \right) E \cdot D r^2 \sin \theta dr d\varphi d\theta \\ &= 2\pi \left( \int_a^b \frac{Q^2}{16\pi^2 \epsilon r^2} dr + \int_b^\infty \frac{Q^2}{16\pi^2 \epsilon_0 r^2} dr \right) \\ &= \frac{Q^2}{8\pi} \left( \frac{1}{\epsilon a} - \frac{1}{\epsilon b} + \frac{1}{\epsilon_0 b} \right) \end{aligned}$$

## 5

The potential in the absence of the dielectric is, according to the book,

$$V(r, \theta) = -E_0 \left( r - \frac{R^3}{r^2} \right) \cos \theta$$

Therefore the field is the negative gradient of this potential:

$$E = E_0 \left[ \left( 1 + 2\frac{R^3}{r^3} \right) \cos \theta \hat{r} - \left( 1 - \frac{R^3}{r^3} \right) \sin \theta \hat{\theta} \right]$$